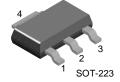


MPSA27/PZTA27

NPN General Purpose Amplifier

- · This device is designed for applications requiring extremely high current gain at collector currents to
- Sourced from process 03.
- · See MPSA28 for characteristics.





1. Emitter 2. Base 3. Collector 1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	60	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	Collector current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_A=25°C unless otherwise noted

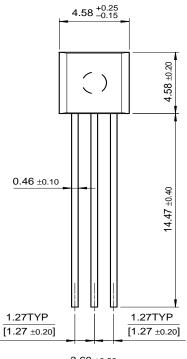
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	eristics					
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = 100 \mu A, V_{BE} = 0$	60			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_C = 0$	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 100 \mu A, I_C = 0$	10			V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 50V, I_{E} = 0$			100	nA
I _{CES}	Collector Cutoff Current	$V_{CE} = 50V, V_{BE} = 0$			500	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 10V, I_{C} = 0$			100	nA
On Characte	eristics	•	•	•		
h _{FE}	DC Current Gain	$I_C = 10$ mA, $V_{CE} = 5.0$ V $I_C = 100$ mA, $V_{CE} = 5.0$ V	10000 10000			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$			1.5	V
V _{BE(on)}	Base-Emitter On Voltage	$I_C = 100 \text{mA}, V_{CE} = 5.0 \text{V}$			2.0	V
	I Characteristics		•	•		
f _T	Current Gain Bandwidth Product	$I_C = 10$ mA, $V_{CE} = 5.0$ V, $f = 100$ MHz	125			MHz

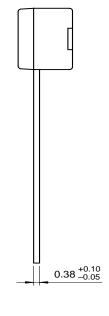
Thermal Characteristics $T_A=25$ °C unless otherwise noted

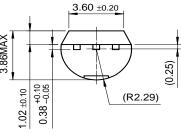
MPSA27	:	Units
IIII OALI	*PZTA27	Units
625	1000	mW
5.0	8.0	mW/°C
83.3		°C/W
200	125	°C/W
	5.0 83.3	5.0 8.0 83.3 200 125

Package Dimensions

TO-92



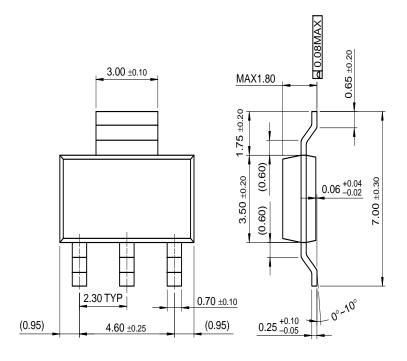


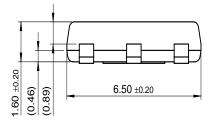


Dimensions in Millimeters

Package Demensions (Continued)

SOT-223





Dimensions in Millimeters

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Bottomless™	FAST [®]	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS^{TM}	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franc	hise™	OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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